Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

KA5x0365RN-SERIES

KA5M0365RN, KA5L0365RN
Fairchild Power Switch(FPS)

Features

- Precision Fixed Operating Frequency (67/50kHz)
- Low Start-up Current(Typ. 100uA)
- Pulse by Pulse Current Limiting
- Over Current Protection
- Over Voltage Protection (Min. 25V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- Auto-Restart Mode

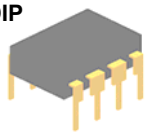
Applications

- SMPS for VCR, SVR, STB, DVD & DVCD
- SMPS for Printer, Facsimile & Scanner
- Adaptor for Camcorder

Description

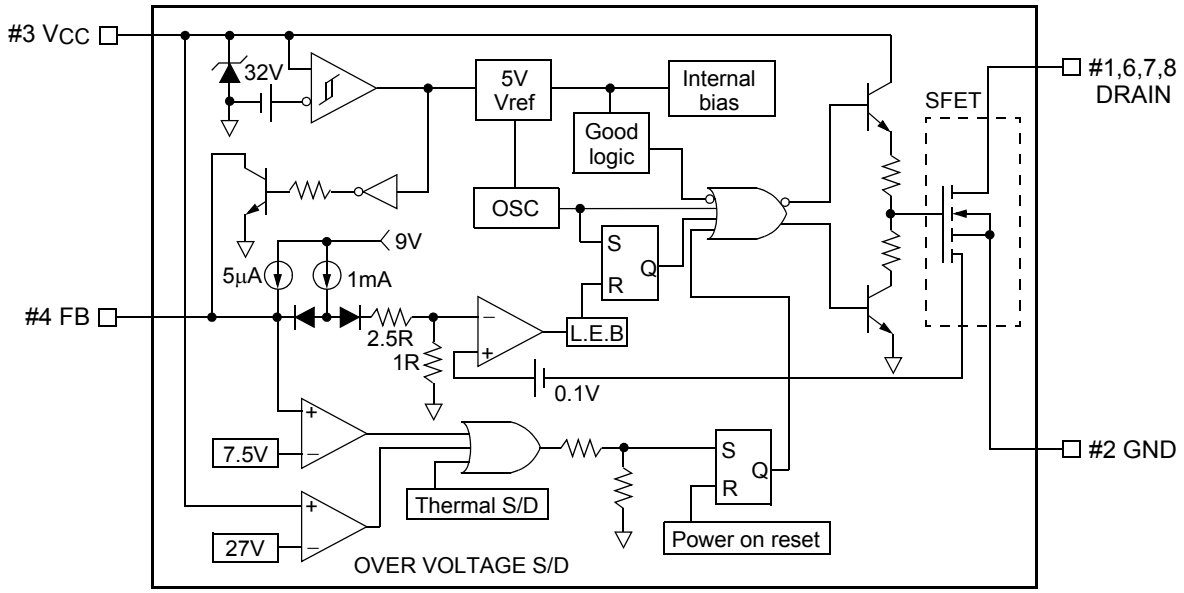
The Fairchild Power Switch(FPS) product family is specially designed for an off-line SMPS with minimal external components. The Fairchild Power Switch(FPS) consists of a high voltage power SenseFET and a current mode PWM IC. Included PWM controller integrates the fixed frequency oscillator, the under voltage lock-out, the leading edge blanking, the optimized gate turn-on/turn-off driver, the thermal shutdown protection, the over voltage protection, and the temperature compensated precision current sources for the loop compensation and the fault protection circuitry. Compared to a discrete MOSFET and a PWM controller or an RCCsolution, a Fairchild Power Switch(FPS) can reduce the total component count, design size and weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for the cost effective design in either a flyback converter or a forward converter

8-DIP



1.6.7.8 Drain 2.GND 3.Vcc 4.FB 5.NC

Internal Block Diagram



Rev.1.0.6

Absolute Maximum Ratings

(Ta=25°C, unless otherwise specified)

Characteristic	Symbol	Value	Unit
KA5M0365RN, KA5L0365RN			
Drain-Gate Voltage (R_{GS}=1MΩ)	V_{DGR}	650	V
Gate-Source (GND) Voltage	V_{GS}	±30	V
Drain Current Pulsed (1)	I_{DM}	3	A_{DC}
Continuous Drain Current (Ta=25°C)	I_D	0.42	A_{DC}
Continuous Drain Current (Ta=100°C)	I_D	0.28	A_{DC}
Single Pulsed Avalanche Energy (2)	E_{AS}	127	mJ
Maximum Supply Voltage	$V_{CC,MAX}$	30	V
Analog Input Voltage Range	V_{FB}	-0.3 to V_{SD}	V
Total Power Dissipation	P_D	1.56	W
	Derating	0.0125	W/°C
Operating Junction Temperature.	T_J	+160	°C
Operating Ambient Temperature.	T_A	-25 to +85	°C
Storage Temperature Range.	T_{STG}	-55 to +150	°C

Note:

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. L = 51mH, starting Tj = 25°C
3. L = 13μH, starting Tj = 25°C

Electrical Characteristics (SenseFET Part)

(Ta = 25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
KA5M0365RN, KA5L0365RN						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=50μA	650	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=Max. Rating, V_{GS}=0V	-	-	50	μA
		V_{DS}=0.8Max. Rating, V_{GS}=0V, T_C=125°C	-	-	200	μA
Static Drain-Source on Resistance (Note)	$R_{DS(ON)}$	V_{GS}=10V, I_D=0.5A	-	3.6	4.5	Ω
Forward Transconductance (Note)	gfs	V_{DS}=50V, I_D=0.5A	2.0	-	-	S
Input Capacitance	Ciss	V_{GS}=0V, V_{DS}=25V, f=1MHz	-	314.9	-	pF
Output Capacitance	Coss		-	47	-	
Reverse Transfer Capacitance	Crss		-	9	-	
Turn On Delay Time	td(on)	V_{DD}=0.5BV_{DSS}, I_D=1.0A (MOSFET switching time is essentially independent of operating temperature)	-	11.2	-	nS
Rise Time	tr		-	34	-	
Turn Off Delay Time	td(off)		-	28.2	-	
Fall Time	tf		-	32	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V_{GS}=10V, I_D=1.0A, V_{DS}=0.5BV_{DSS} (MOSFET switching time is essentially independent of operating temperature)			11.93	nC
Gate-Source Charge	Qgs		-	1.95	-	
Gate-Drain (Miller) Charge	Qgd			6.85		

Note:

1. Pulse test: Pulse width ≤ 300μS, duty ≤ 2%
2. $S = \frac{1}{R}$

Electrical Characteristics (Control Part) (Continued)

(Ta = 25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Typ.	Max.	Unit
UVLO SECTION						
Start Threshold Voltage	V_{START}	V_{FB}=GND	14	15	16	V
Stop Threshold Voltage	V_{STOP}	V_{FB}=GND	8.4	9	9.6	V
OSCILLATOR SECTION						
Initial Accuracy	F_{OSC}	**KA5M0365RN**	61	67	73	kHz
Initial Accuracy	F_{OSC}	**KA5L0365RN**	45	50	55	kHz
Frequency Change With Temperature (2)	-	-25°C≤Ta≤+85°C	-	±5	±10	%
Maximum Duty Cycle	Dmax		72	77	82	%
FEEDBACK SECTION						
Feedback Source Current	I_{FB}	Ta=25°C, 0V≤Vfb≤3V	0.7	0.9	1.1	mA
Shutdown Feedback Voltage	V_{SD}	Vfb≥6.5V	6.9	7.5	8.1	V
Shutdown Delay Current	Idelay	Ta=25°C, 5V≤Vfb≤V_{SD}	4	5	6	μA
REFERENCE SECTION						
Output Voltage (1)	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability (1)(2)	Vref/ΔT	-25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
CURRENT LIMIT(SELF-PROTECTION)SECTION						
Peak Current Limit	I_{OVER}	Max. inductor current	1.89	2.15	2.41	A
PROTECTION SECTION						
Over Voltage Protection	V_{OVP}	V_{CC}≥24V	25	27	29	V
Thermal Shutdown Temperature (Tj) (1)	T_{SD}	-	140	160	-	°C
TOTAL STANDBY CURRENT SECTION						
Start-up Current	I_{START}	V_{CC}=14V	-	100	170	μA
Operating Supply Current (Control Part Only)	I_{OP}	V_{CC}≤28	-	7	12	mA

Note:

1. These parameters, although guaranteed, are not 100% tested in production
2. These parameters, although guaranteed, are tested in EDS(water test) process

Typical Performance Characteristics(SenseFET part) (Continued)

(KA5M0365RN, KA5L0365RN)

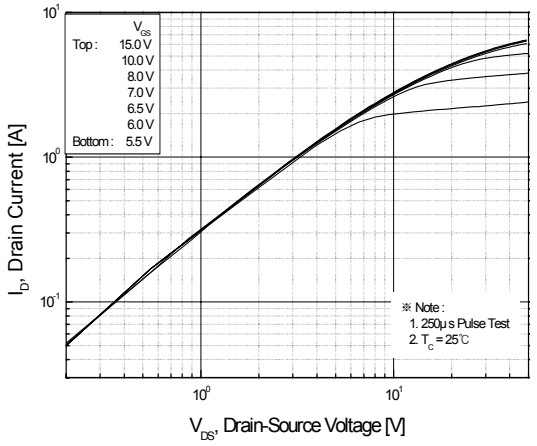


Figure 1. Output Characteristics

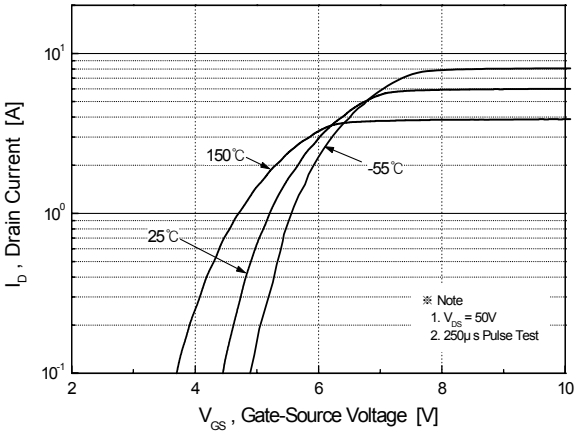


Figure 2. Transfer Characteristics

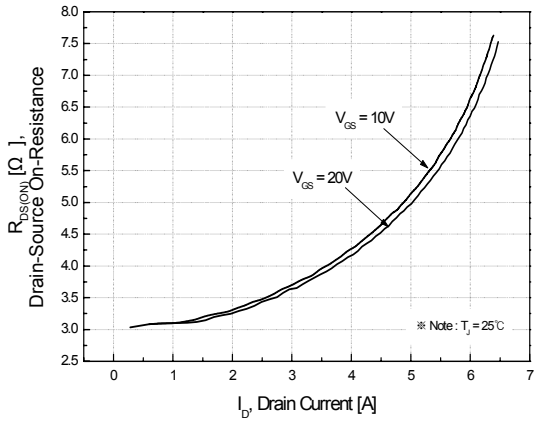


Figure 3. On-Resistance vs. Drain Current

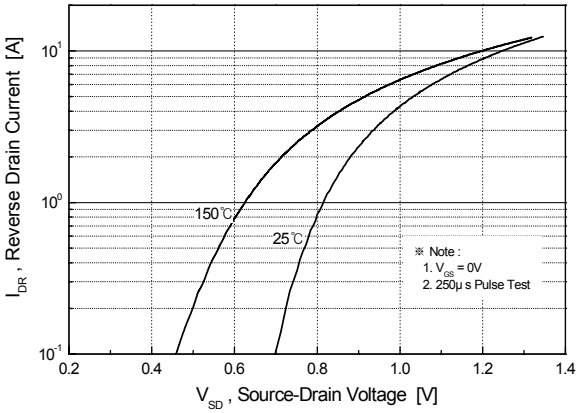


Figure 4. Source-Drain Diode Forward Voltage

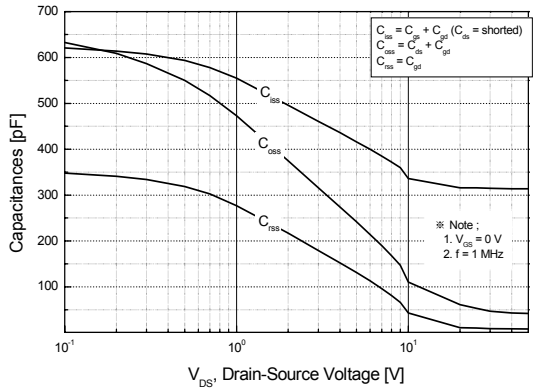


Figure 5. Capacitance vs. Drain-Source Voltage

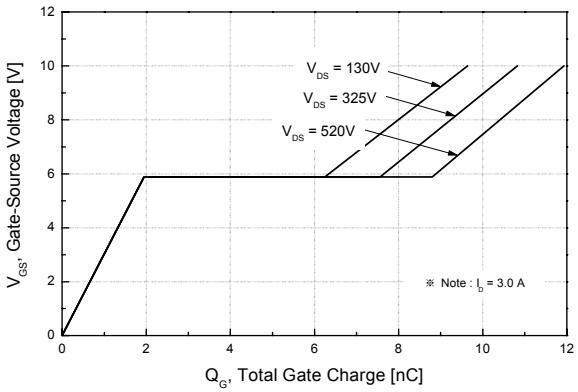


Figure 6. Gate Charge vs. Gate-Source Voltage

Typical Performance Characteristics (Continued)

(KA5M0365RN, KA5L0365RN)

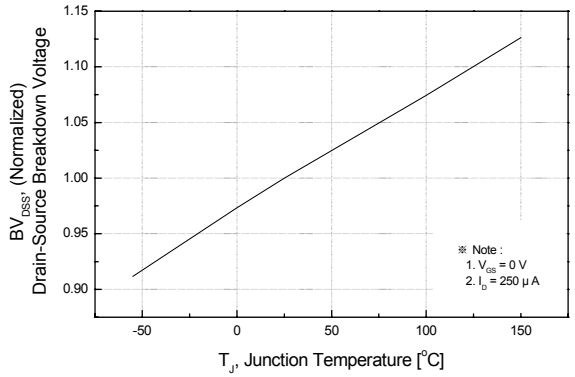


Figure 7. Breakdown Voltage vs. Temperature

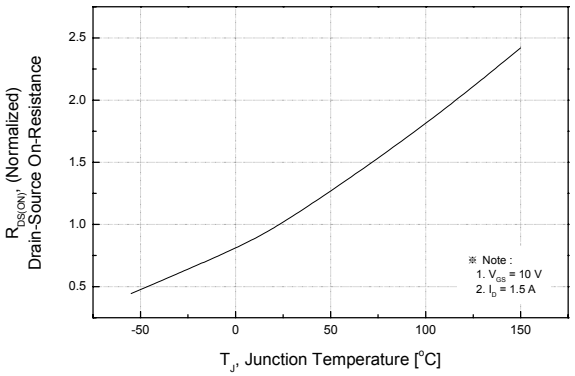


Figure 8. On-Resistance vs. Temperature

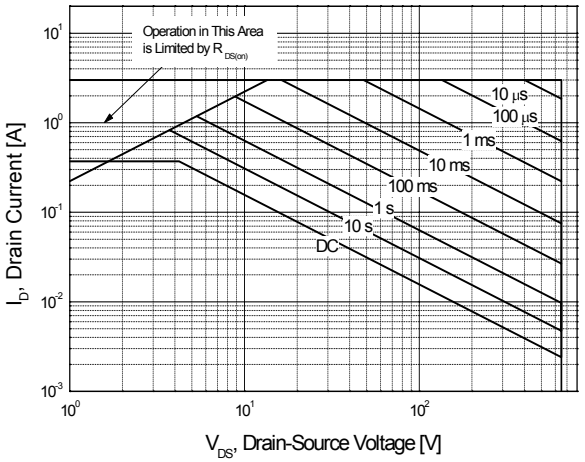


Figure 9. Max. Safe Operating Area

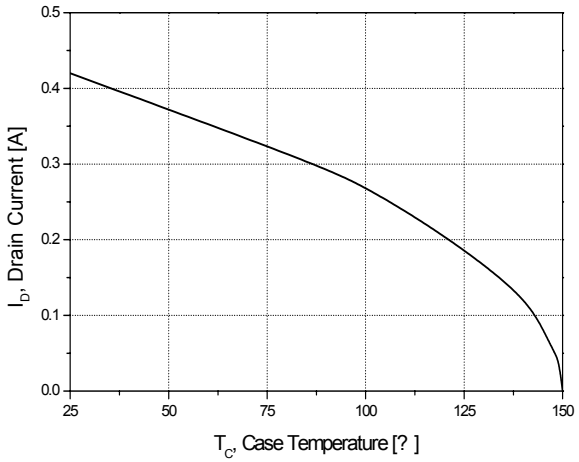


Figure 10. Max. Drain Current vs. Case Temperature

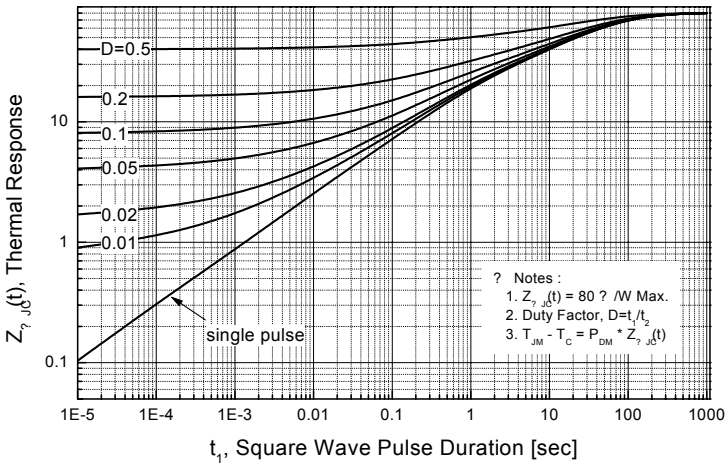


Figure 11. Thermal Response

Typical Performance Characteristics (Control Part) (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

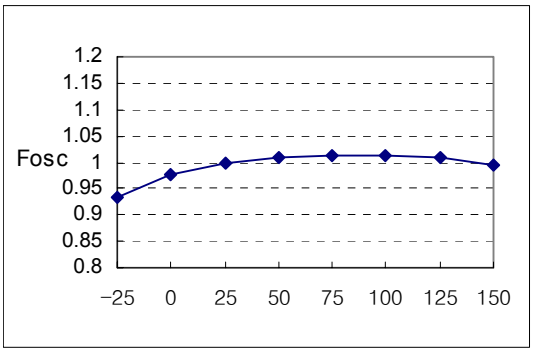


Figure 1. Operating Frequency

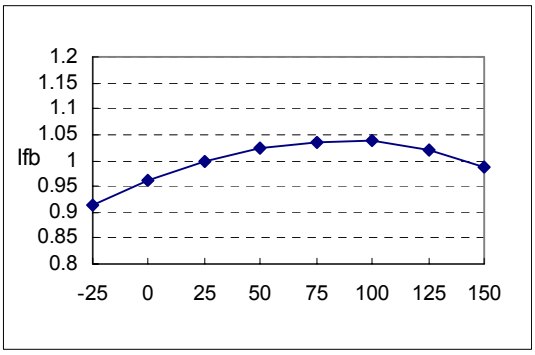


Figure 2. Feedback Source Current

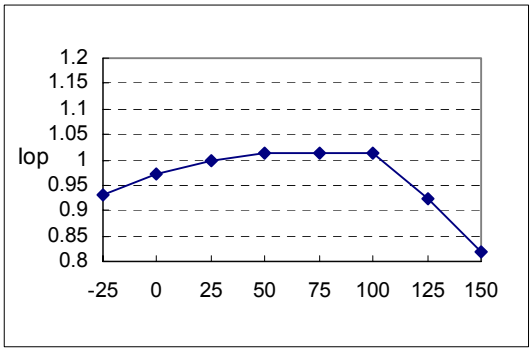


Figure 3. Operating Supply Current

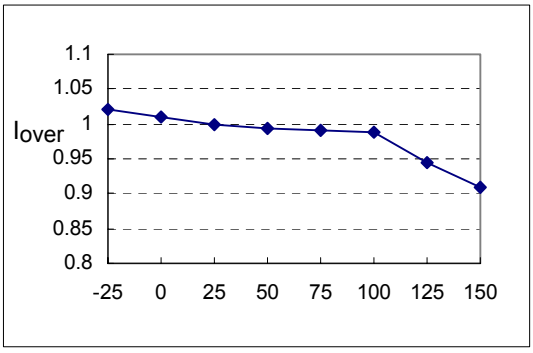


Figure 4. Peak Current Limit

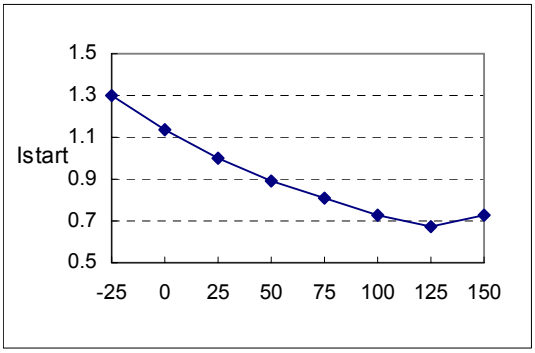


Figure 5. Start up Current

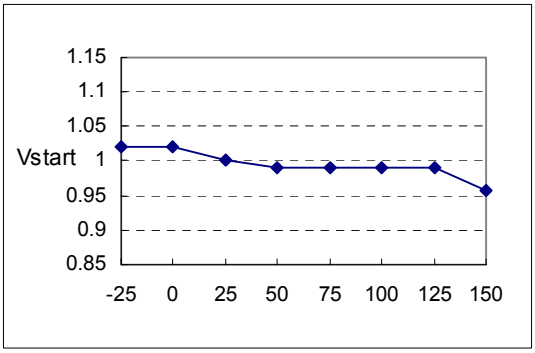


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

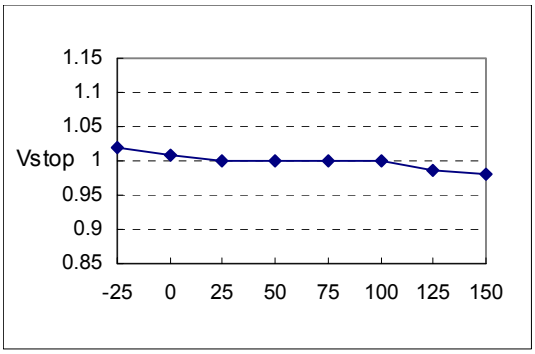


Figure 7. Stop Threshold Voltage

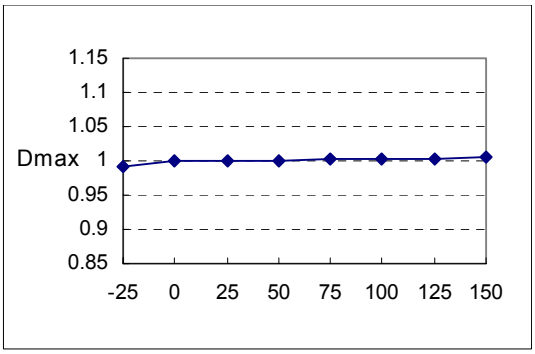


Figure 8. Maximum Duty Cycle

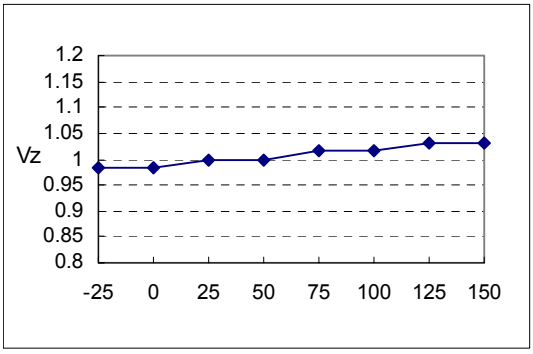


Figure 9. V_{CC} Zener Voltage

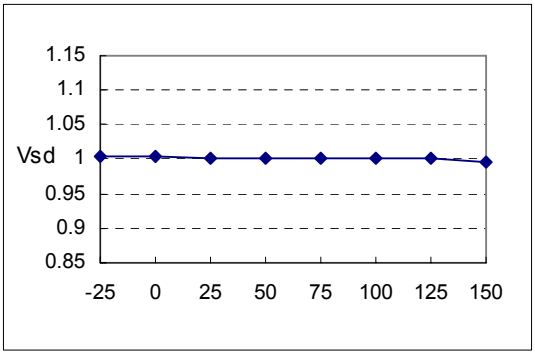


Figure 10. Shutdown Feedback Voltage

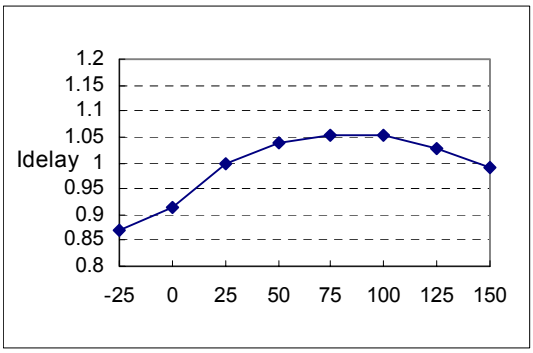


Figure 11. Shutdown Delay Current

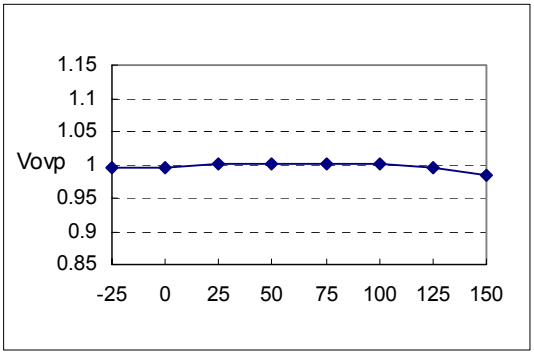


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

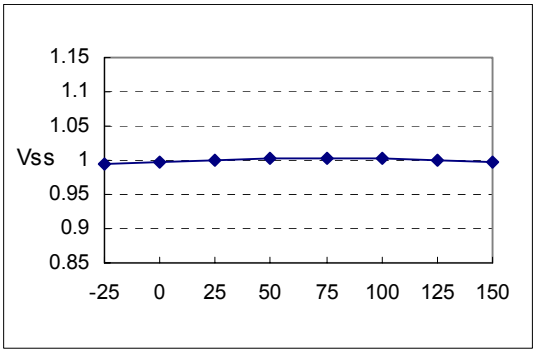


Figure13. Soft Start Voltage

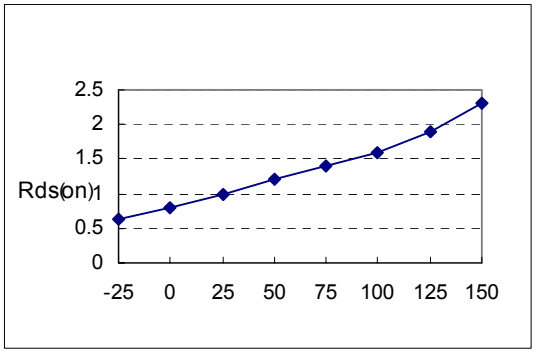
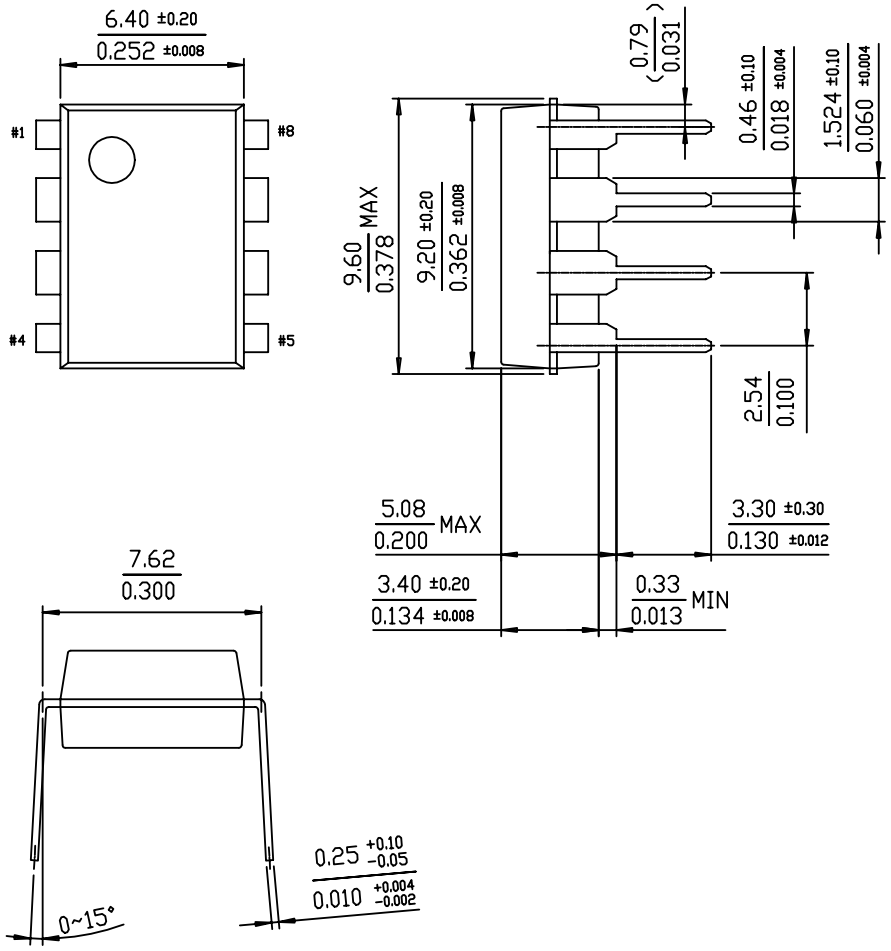


Figure 14. Static Drain-Source on Resistance

Package Dimensions

8-DIP



Ordering Information

Product Number	Package	Marking Code	BV_{DSS}	F_{OSC}	$R_{DS(on)}$
KA5M0365RN	8-DIP	5M0365R	650V	67kHz	3.6Ω
KA5L0365RN	8-DIP	5L0365R	650V	50kHz	3.6Ω

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.